











DS8921, DS8921A, DS8921AT

SNLS374D -MAY 1998-REVISED JANUARY 2015

DS8921x Differential Line Driver and Receiver Pair

Features

- 12-ns Typical Propagation Delay
- Output Skew: 0.5 ns Typical
- Meets the Requirements of EIA Standard RS-422
- **Complementary Driver Outputs**
- High Differential or Common-Mode Input Voltage Ranges of ±7 V
- ±0.2 V Receiver Sensitivity Over the Input Voltage
- Receiver Input Hysteresis: 70 mV Typical
- DS8921AT Industrial Temperature Operation: (-40°C to +85°C)

2 Applications

- Differential Line Driver and Receiver for:
 - ST506 Disk Drive Standard
 - ST412 Disk Drive Standard
 - **ESDI Disk Drive Standard**
 - RS-422 Interface

3 Description

The DS8921, DS8921A, and DS8921AT devices are differential line driver and receiver pairs designed specifically for applications meeting the ST506, ST412, and ESDI disk drive standards. In addition, these devices meet the requirements of the EIA standard RS-422.

The DS8921x receivers offer an input sensitivity of 200 mV over a ±7 V common mode operating range. Hysteresis is incorporated (typically 70 mV) to improve noise margin for slowly changing input waveforms.

The DS8921x drivers are designed to provide unipolar differential drive to twisted-pair or parallel wire transmission lines. Complementary outputs are logically ANDed and provide an output skew of 0.5 ns (typical) with propagation delays of 12 ns.

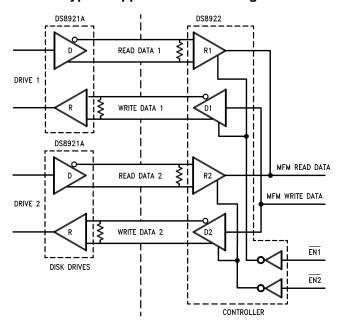
The DS8921x devices are designed to be compatible with TTL and CMOS.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
DS8921	SOIC (8)	4.90 mm x 3.91 mm
DS8921A DS8921AT	PDIP (8)	9.81 mm x 6.35 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Typical Application Block Diagram



Simplified Functional Block Diagram

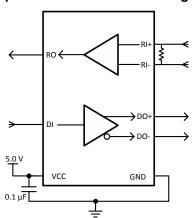




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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (April 2013) to Revision D

Page

Changes from Revision B (November 2004) to Revision C

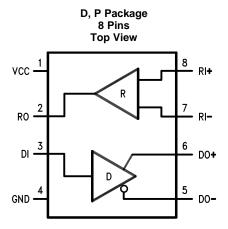
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5 Pin Configuration and Functions



Pin Functions

Р	IN					
		I/O	DESCRIPTION			
NAME	NO.					
DIFFERENTIA	DIFFERENTIAL SIGNALING I/O					
DI	3	1	TTL/CMOS Compatible Driver Input			
DO+, DO-	6, 5	0	Inverting and non-inverting differential driver outputs			
RI+, RI-	8, 7	I	Inverting and non-inverting differential receiver inputs			
RO	2	0	Receiver Output Pin			
POWER	•	•				
GND	4	Power	Ground Pin			
VCC	1	Power	Supply pin, provide 5-V supply			

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾⁽²⁾

	MIN	MAX	UNIT
Supply Voltage		7	V
Driver Input Voltage	-0.5	7	V
Output Voltage		5.5	V
Receiver Output Sink Current		50	mA
Receiver Input Voltage	-10	10	V
Differential Input Voltage	-12	12	V
Maximum Package Power Dissipation at 25°C: D Package		730	mW
Maximum Package Power Dissipation at 25°C: P Package		1160	mW
Derate D Package, above 25°C		9.3	mW/°C
Derate P Package, above 25°C		5.8	mW/°C
Lead Temperature		260	°C
(Soldering, 4 sec.)		260	°C
Maximum Junction Temperature		150	°C
Storage Temperature, T _{stg}	-65	165	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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⁽²⁾ If Military/Aerospace specified devices are required, please contact the Texas Instrument Sales Office/ Distributors for availability and specifications.



6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

	MIN	MAX	UNIT
Supply Voltage	4.5	5.5	V
Temperature (T _A): DS8921/DS8921A	0	70	°C
Temperature (T _A): DS8921AT	-40	85	°C

6.4 Electrical Characteristics

Over operating free-air temperature range unless otherwise noted. (1)(2)(3)

	TEST CONDITIONS	MIN	TYP	MAX	UNIT
RECEIVE	ER .	<u>'</u>			
V _{TH}	-7 V ≤ V _{CM} ≤ +7 V	-200	±35	+200	mV
V _{HYST}	-7 V ≤ V _{CM} ≤ +7 V	15	70		mV
R _{IN}	$V_{IN} = -7 \text{ V}$, +7 V, (Other Input = GND)	4.0	6.0		kΩ
ı	V _{IN} = 10 V			3.25	mA
I _{IN}	V _{IN} = −10 V			-3.25	mA
V _{OH}	I _{OH} = -400 μA	2.5			V
V _{OL}	$I_{OL} = 8 \text{ mA}$			0.5	V
I _{SC}	$V_{CC} = MAX, V_{OUT} = 0 V$	-15		-100	mA
DRIVER		· ·		, , , , , , , , , , , , , , , , , , ,	
V_{IH}		2.0			V
V_{IL}				0.8	V
I _{IL}	$V_{CC} = MAX$, $V_{IN} = 0.4 V$		-40	-200	μΑ
I _{IH}	$V_{CC} = MAX$, $V_{IN} = 2.7 V$			20	μΑ
I	$V_{CC} = MAX$, $V_{IN} = 7.0 V$			100	μΑ
V_{CL}	$V_{CC} = MIN$, $I_{IN} = -18 \text{ mA}$			-1.5	V
V_{OH}	$V_{CC} = MIN, I_{OH} = -20 \text{ mA}$	2.5			V
V _{OL}	$V_{CC} = MIN$, $I_{OL} = +20 \text{ mA}$			0.5	V
I _{OFF}	$V_{CC} = 0V, V_{OUT} = 5.5 V$			100	μΑ
$ V_T - \overline{VT} $	Ī			0.4	V
V _T		2.0			V
$ V_{OS} - \overline{V}_{C} $	osl			0.4	V
I _{SC}	V _{CC} = MAX, V _{OUT} = 0 V	-30		-150	mA
DRIVER	AND RECEIVER				
Icc	V _{CC} = MAX, V _{OUT} = Logic 0			35	mA

⁽¹⁾ All currents into device pins are shown as positive values; all currents out of the device are shown as negative; all voltages are referenced to ground unless otherwise specified. All values shown as max or min are classified on absolute value basis.

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⁽²⁾ All typical values are V_{CC} = 5 V, T_A = 25°C.

⁽³⁾ Only one output at a time should be shorted.



6.5 Receiver Switching Characteristics

	TEST CONDITIONS	MIN	TYP	MAX 8921	MAX 8921A	MAX 8921AT	UNIT
t _{pLH}	C _L = 30 pF		14	22.5	20	20	ns
	(Figure 3 and Figure 4)						
t _{pHL}	C _L = 30 pF		14	22.5	20	20	ns
	(Figure 3 and Figure 4)						
t _{pLH} -t _{pHL}	C _L = 30 pF		0.5	5	3.5	5	ns
	(Figure 3 and Figure 4)						

6.6 Driver Switching Characteristics: Single-Ended Characteristics

	TEST CONDITIONS	MIN	TYP	MAX 8921	MAX 8921A	MAX 8921AT	UNIT
t _{pLH}	$C_L = 30 \text{ pF}$		10	15	15	15	ns
	(Figure 5 and Figure 6)						
t _{pHL}	$C_L = 30 \text{ pF}$		10	15	15	15	ns
	(Figure 5 and Figure 6)						
t _{TLH}	$C_L = 30 \text{ pF}$		5	8	8	9.5	ns
	(Figure 9 and Figure 10)						
t _{THL}	$C_L = 30 \text{ pF}$		5	8	8	9.5	ns
	(Figure 9 and Figure 10)						
Skew	CL = 30 pF ⁽¹⁾		1	5	3.5	3.5	ns
	(Figure 5 and Figure 6)						

⁽¹⁾ Difference between complementary outputs at the 50% point.

6.7 Driver Switching Characteristics: Differential Characteristics⁽¹⁾

	TEST CONDITIONS	MIN	TYP	MAX 8921	MAX 8921A	MAX 8921AT	UNIT
t _{pLH}	C _L = 30 pF		10	15	15	15	ns
	(Figure 5, Figure 7, and Figure 8)						
t_{pHL}	C _L = 30 pF		10	15	15	15	ns
	(Figure 5, Figure 7, and Figure 8)						
t _{pLH} -t _{pHL}	$C_L = 30 \text{ pF}$		0.5	6	2.75	2.75	ns
	(Figure 5, Figure 7, and Figure 8)						

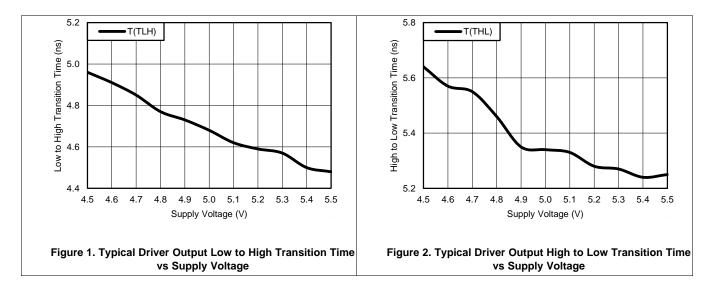
(1) Differential Delays are defined as calculated results from single ended rise and fall time measurements. This approach in establishing AC performance specifications has been taken due to limitations of available Automatic Test Equipment (ATE). The calculated ATE results assume a linear transition between measurement points and are a result of the following equations: $T_{cr} = \text{Crossing Point} \quad T_{ra}, T_{rb}, T_{fa} \text{ and } T_{fb} \text{ are time measurements with respect to the input. See Figure 8.}$

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6.8 Typical Characteristics

Test Setup: Figure 5. Data Rate, Test Pattern: 2 Mbps, 1010 Pattern. T: 25°C



7 Parameter Measurement Information

7.1 AC Test Circuits and Switching Diagrams

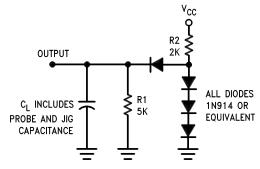


Figure 3. Test Circuit for Receiver Output

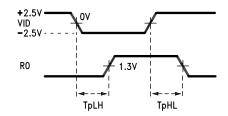


Figure 4. Receiver Propagation Delay

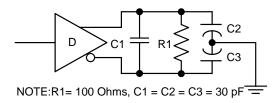


Figure 5. Driver Test Circuit



AC Test Circuits and Switching Diagrams (continued)

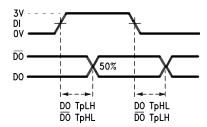


Figure 6. Driver Single-Ended Propagation Delay

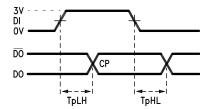


Figure 7. Driver Differential Propagation Delay

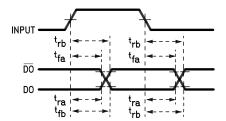


Figure 8. Driver Delay ATE Testing

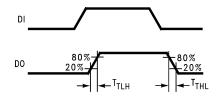


Figure 9. Driver Output Transition Time

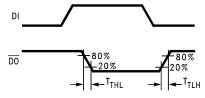


Figure 10. Driver Output Transition Time

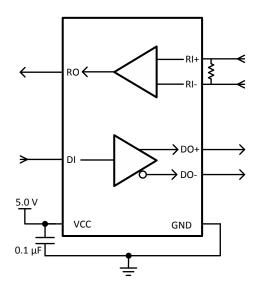


8 Detailed Description

8.1 Overview

The DS8921x devices are each a differential line driver and receiver pair in a single package. The devices are designed specifically for ST506, ST412, and ESDI disk drive standards, as well as RS-422 interface applications. The DS8921 and DS8921A are rated at a commercial temperature range of 0°C to 70°C, whereas the DS8921AT is rated at an extended temperature range of -40°C to +85°C.

8.2 Functional Block Diagram



8.3 Feature Description

The DS8921x devices each contain a differential driver and receiver.

The driver converts a TTL or CMOS input to complementary outputs that provide differential drive to a twisted-pair or parallel wire transmission line. The receiver converts the differential signals at its input pins to a TTL output. The receiver offers an input sensitivity of ±200 mV and supports a common-mode input voltage of ±7 V.

8.4 Device Functional Modes

Table 1. Function Table

REC	EIVER	DRIVER			
INPUT	OUTPUT	INPUT	OUT	PUT	
RI+, RI-	RO	DI	DO+	DO-	
$V_{ID}^{(1)} \ge V_{TH} (MAX)$	1	1	1	0	
$V_{ID}^{(1)} \le V_{TH} (MIN)$	0	0	0	1	
Open	1				

(1) V_{ID} is the input differential voltage between RI+ and RI-.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The DS8921 is a differential line driver and receiver pair in a single package, designed for applications for the ST506, ST412, and ESDI Disk Drive Standards. The DS8921 is compatible to EIA RS-422 signaling standards, supporting 200-mV input sensitivity across a ±7-V common mode operating range. This transceiver is intended for driving differential signal across long transmission lines and translating received differential signals into their CMOS/TTL single-ended equivalence. The DS8921 transmits and reproduces received data in communications links where ground reference difference, or noisy environment are common.

9.2 Typical Application

Figure 11 shows a typical implementation of the DS8921x device in a ST506 and ST412 disk drive application. The differential outputs of the driver are connected to a twisted-pair transmission line, carrying data from the driver to the differential receiver at the other end of the cable. A differential termination resistor should be connected across the input pins of the receiver.

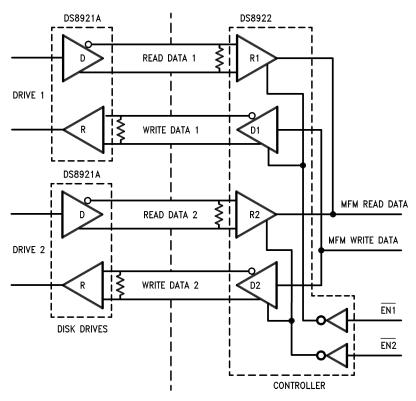


Figure 11. ST506 and ST412 Application



Typical Application (continued)

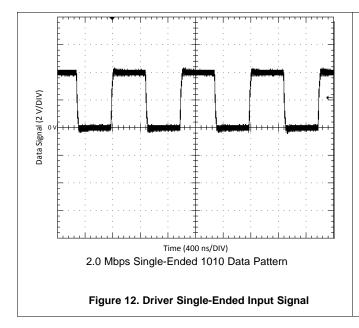
9.2.1 Design Requirements

- Apply TTL or LVCMOS signal to driver input at DI
- Transmit complementary outputs at DO+ and DO-
- · Receive complimentary input signals at RI+ and RI-
- Receive TTL output signal at RO
- Use controlled-impedance transmission lines such as printed circuit board traces, twisted-pair wires or parallel wire cable
- Place terminating resistor at the far end of the differential pair

9.2.2 Detailed Design Procedure

- Connect VCC and GND pins to the power and ground planes of the printed circuit board, with 0.1-uF bypass capacitor
- Use TTL/LVCMOS logic levels at DI and RO
- Use controlled-impedance transmission media for the differential signals DI+- and RO+-
- Place a terminating resistor at the far-end of the differential pair to avoid reflection
- Ensure the received complimentary signals at RO+ and RO- are within the signal threshold of ±200 mV

9.2.3 Application Curves



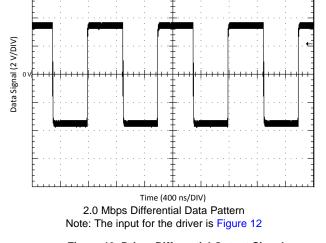
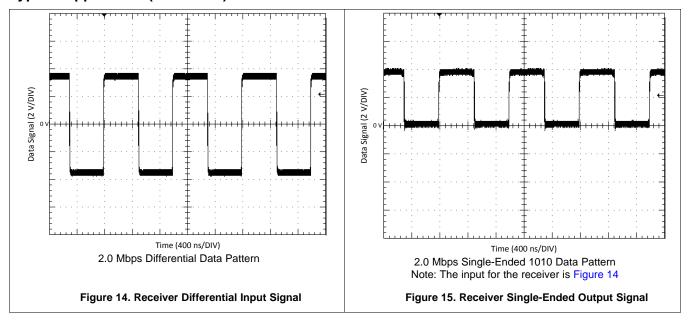


Figure 13. Driver Differential Output Signal



Typical Application (continued)





10 Power Supply Recommendations

TI recommends connecting the supply (VCC) and ground (GND) pins to power planes that are routed on adjacent layers of the PCB. Additionally, careful attention should be paid to bypassing the supply using a capacitor. A 0.1-µF bypass capacitor should be connected to the VCC pin such that the capacitor is as close as possible to the device.

11 Layout

11.1 Layout Guidelines

High-speed interconnects should be treated as transmission lines with a controlled impedance. The differential interconnect can be a pair of printed-circuit board (PCB) traces, twisted-pair wires, or a parallel wire cable. A termination resistor should be placed at the differential input, and the resistor value should be approximately the same as the differential impedance of the transmission line to minimize reflections.

It is preferable to connect the VCC and GND pins to the power and ground planes using plated-through-holes. Additionally, a 0.1-µF bypass capacitor should be placed close to the VCC pin across VCC and GND.

Place a terminating resistor at the receiving end of the interconnect transmission line, as close as possible to the input pins of the receiver. The terminating resistor value should be approximately the same as the differential pair impedance to minimize reflection, and the transmission line should have a controlled impedance with minimum impedance discontinuities.

The input and output differential signals of the device should have traces that are routed exclusively on one layer of the board, and the differential pairs should also be routed away from other differential pairs in order to minimize crosstalk between transmission lines. Additionally, the differential pairs should have a controlled impedance with minimum impedance discontinuities and be terminated with a resistor that is closely matched to the differential pair impedance in order to minimize transmission line reflections. The differential pairs should be routed with uniform trace width and spacing to minimize impedance mismatch.

11.2 Layout Example

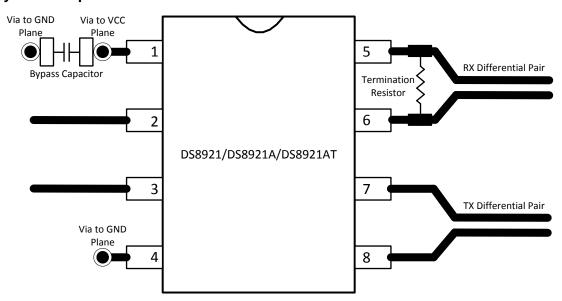


Figure 16. DS8921 Example Layout



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
DS8921	Click here	Click here	Click here	Click here	Click here
DS8921A	Click here	Click here	Click here	Click here	Click here
DS8921AT	Click here	Click here	Click here	Click here	Click here

12.2 Trademarks

All trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
DS8921AM/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS89 21AM
DS8921AM/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS89 21AM
DS8921AMX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS89 21AM
DS8921AMX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS89 21AM
DS8921ATM/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS892 1ATM
DS8921ATM/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS892 1ATM
DS8921ATMX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS892 1ATM
DS8921ATMX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	DS892 1ATM
DS8921M/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS892 1M
DS8921M/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS892 1M
DS8921MX/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS892 1M
DS8921MX/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	DS892 1M

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

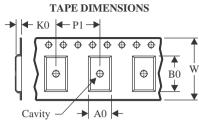
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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

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TAPE AND REEL INFORMATION

REEL DIMENSIONS Reel Diameter Reel Width (W1)



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

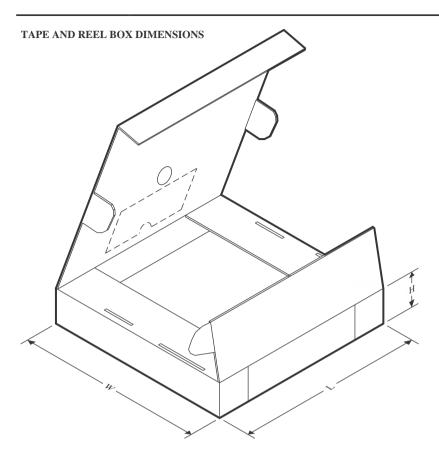


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS8921AMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
DS8921ATMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
DS8921MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1



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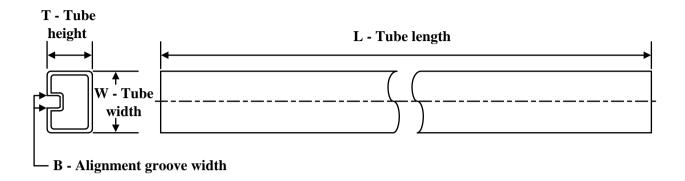
*All dimensions are nominal

Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
DS8921AMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0	
DS8921ATMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0	
DS8921MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0	

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
DS8921AM/NOPB	D	SOIC	8	95	495	8	4064	3.05
DS8921AM/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
DS8921ATM/NOPB	D	SOIC	8	95	495	8	4064	3.05
DS8921ATM/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
DS8921M/NOPB	D	SOIC	8	95	495	8	4064	3.05
DS8921M/NOPB.B	D	SOIC	8	95	495	8	4064	3.05



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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